

QUADRUPLE OPERATIONAL AMPLIFIERS

- LOW SUPPLY CURRENT: 0.53mA/AMPLI-FIFR
- CLASS AB OUTPUT STAGE: NO CROSS **OVER DISTORTION**
- PIN COMPATIBLE WITH LM124
- LOW INPUT OFFSET VOLTAGE: 1mV
- LOW INPUT OFFSET CURRENT: 2nA
- LOW INPUT BIAS CURRENT: 30nA
- GAIN BANDWIDTH PRODUCT: 1.3MHz
- HIGH DEGREE OF ISOLATION BETWEEN AMPLIFIERS: 120dB
- OVERLOAD PROTECTION FOR INPUTS AND OUTPUTS

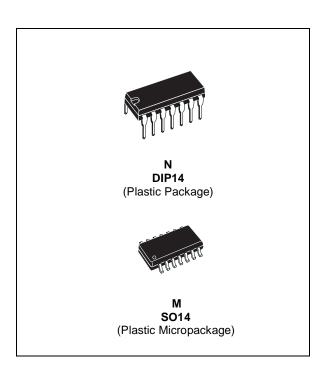
DESCRIPTION

The LM148 consists of four independent, high gain internally compensated, low power operational amplifiers which have been designed to provide functional characteristics identical to those of the familiar UA741 operational amplifier. In addition the total supply current for all four amplifiers is compatible to the supply current of a single UA741 type op amp. Other features include input offset current and input bias current which are much less than those of a standard UA741. Also, excellent isolation between amplifiers has been achieved by independently biasing each amplifier and using layout techniques ghich minimize thermal coupling.

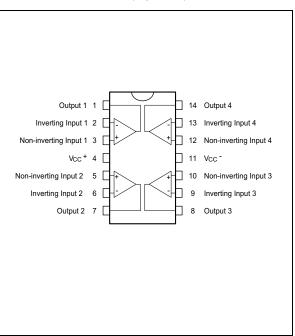
ORDER CODE

Part	Temperature Range	Package			
Number		N	М		
LM148	-55°C, +125°C	•	•		
LM248	-40°C, +105°C	•	•		
LM348	0°C, +70°C	•	•		
Example: LM348D					

N = Dual in Line Package (DIP)
 M = Small Outline Package (SO) - also available in Tape & Reel (DT)

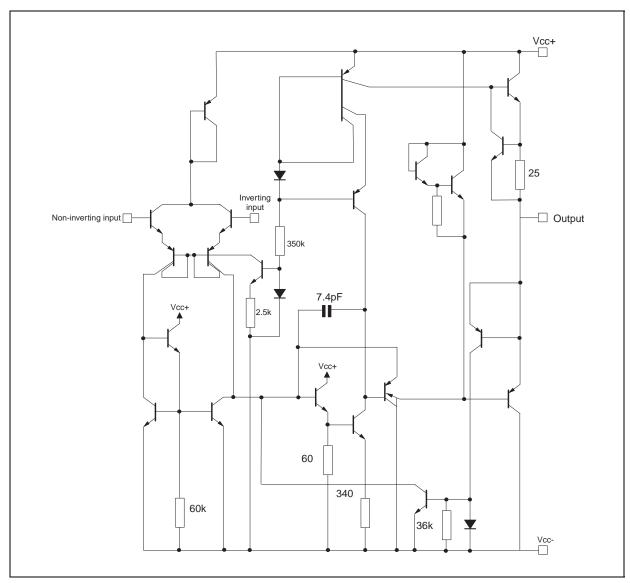


PIN CONNECTIONS (top view)





SCHEMATIC DIAGRAM



ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	LM148	LM248	LM348	Unit
V _{CC}	Supply voltage		±22		
V _i	Input Voltage 1)		±22		
V _{id}	Differential Input Voltage		±44		
	Output Short-circuit Duration 2)		Infinite		
P _{tot}	Power Dissipation		500		
T _{oper}	Operating Free-air Temperature Range	-55 to +125	-40 to +105	0 to +70	°C
T _{stg}	Storage Temperature Range		-65 to +150		

^{1.} For supply voltage less than maximum value, the absolute maximum input voltage is equal to the supply voltage.

^{2.} Any of the amplifier outputs can be shorted to ground indefinitly; however more than one should not be simultaneously shorted as the maximum junction will be exceeded.



ELECTRICAL CHARACTERISTICS

 $V_{CC} = \pm 15V$, $T_{amb} = 25$ °C (unless otherwise specified)

Symbol	Parameter	Min.	Тур.	Max.	Unit
V_{io}	Input Offset Voltage ($R_s \le 10k\Omega$) $T_{amb} = 25$ °C $T_{min} \le T_{amb} \le T_{max}$		1	5 6	mV
l _{io}	Input Offset Current $T_{amb} = 25^{\circ}C$ $T_{min} \le T_{amb} \le T_{max}$		2	25 75	nA
l _{ib}	Input Bias Current $T_{amb} = 25^{\circ}C$ $T_{min} \le T_{amb} \le T_{max}$		30	100 300	nA
A _{vd}	Large Signal Voltage Gain ($V_0 = \pm 10V$, $R_L = 2k\Omega$) $T_{amb} = 25^{\circ}C$ $T_{min} \le T_{amb} \le T_{max}$	50 25	160		V/mV
SVR	Supply Voltage Rejection Ratio ($R_s \le 10k\Omega$) $T_{amb} = 25^{\circ}C$ $T_{min} \le T_{amb} \le T_{max}$	77 77	100		dB
I _{cc}	Supply Current, all Amp, no load $T_{amb} = 25^{\circ}C$ $T_{min} \le T_{amb} \le T_{max}$		2.1	3.6 4.8	mA
V _{icm}	Input Common Mode Voltage Range $ T_{amb} = 25^{\circ}C $ $ T_{min} \leq T_{amb} \leq T_{max} $	±12 ±12			
CMR	Common Mode Rejection Ratio ($R_S \le 10k\Omega$) $T_{amb} = 25^{\circ}C$ $T_{min} \le T_{amb} \le T_{max}$	70 70	110		dB
I _{os}	Output Short-circuit Current T _{amb} = 25°C	10	25	35	mA
±V _{opp}	$ \begin{array}{ll} \text{Output Voltage Swing} \\ T_{amb} = 25^{\circ}\text{C} & R_{L} \leq 10 k\Omega \\ R_{L} \leq 2 k\Omega \\ T_{min} \leq T_{amb} \leq T_{max} & R_{L} \leq 10 k\Omega \\ R_{L} \leq 2 k\Omega \end{array} $	12 10 12 10	13 12		V
SR	Slew Rate ($V_I = \pm 10V$, $R_L = 10k\Omega$, $C_L = 100pF$, unity Gain)	0.25	0.5		V/µs
t _r	Rsie Time ($V_I = \pm 10V$, $R_L = 10k\Omega$, $C_L = 100pF$, unity Gain)		0.3		μs
K _{OV}	Overshoot ($V_I = \pm 10V$, $R_L = 10k\Omega$, $C_L = 100pF$, unity Gain)		5		%
R _I	Input Resistance	0.8	2.5		ΜΩ
GBP	Gain Bandwith Product (V _I = 10 mV, R _L = 10k Ω , C _L = 100pF f =100kHz)	0.7	1.3		MHz
THD	Total Harmonic Distortion (f = 1kHz, A_v = 20dB, R_L = 10k Ω C_L = 100pF, V_o = 2 V_{pp})		0.08		%
e _n	Equivalent Input Noise Voltage (f = 1kHz, $R_s = 100\Omega$		40		$\frac{\text{nV}}{\sqrt{\text{Hz}}}$
V _{o1} /V _{o2}	Channel Separation		120		dB



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